

RoHS Directive compatibility information
<http://www.mew.co.jp/ac/e/environment/>

FEATURES

- Controls low-level analog signals**
PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
- Controlled with low-level input signals**
- Controls various types of loads such as relays, motors, lamps and solenoids.**
- Optical coupling for extremely high isolation**
Unlike mechanical relays, the PhotoMOS relay combines LED and optoelectronic device to transfer signals using light for extremely high isolation.
- Eliminates the need for a counter electromotive force protection diode in the drive circuits on the input side**
- Stable on resistance**

- Low-level off state leakage current**
- Eliminates the need for a power supply to drive the power MOSFET**
A power supply used to drive the power MOSFET is unnecessary because of the built-in optoelectronic device. This results in easy circuit design and small PC board area.
- Low thermal electromotive force (Approx. 1 μ V)**

TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephone equipment
- Data communication equipment
- Computer

TYPES

1. DC type (AQV10 types)

Output rating*		Part No.				Packing quantity	
		Through hole terminal	Surface-mount terminal		Tape and reel packing style		
Load voltage	Load current		Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube
40 V	700 mA	AQV101	AQV101A	AQV101AX	AQV101AZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs
60 V	600 mA	AQV102	AQV102A	AQV102AX	AQV102AZ		
250 V	300 mA	AQV103	AQV103A	AQV103AX	AQV103AZ		
400 V	180 mA	AQV104	AQV104A	AQV104AX	AQV104AZ		

*Indicate the peak AC and DC values.

Note: For space reasons, the package style indicator "X" or "Z" are not marked on the relay.

2. AC/DC type (AQV20 types)

Output rating*		Part No.				Packing quantity	
		Through hole terminal	Surface-mount terminal		Tape and reel packing style		
Load voltage	Load current		Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube
40 V	500 mA	AQV201	AQV201A	AQV201AX	AQV201AZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs
60 V	400 mA	AQV202	AQV202A	AQV202AX	AQV202AZ		
250 V	200 mA	AQV203	AQV203A	AQV203AX	AQV203AZ		
400 V	150 mA	AQV204	AQV204A	AQV204AX	AQV204AZ		

*Indicate the peak AC and DC values.

Note: For space reasons, the SMD terminal shape indicator "A" and the package style indicator "X" or "Z" are not marked on the relay.

HF PhotoMOS (AQV10○, 20○)

RATING

1. DC type (AQV10 types)

1) Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQV101(A)	AQV102(A)	AQV103(A)	AQV104(A)	Remarks
Input	LED forward current	I_F	50 mA				
	LED reverse voltage	V_R	10 V				
	Peak forward current	I_{FP}	1 A				f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P_{in}	150 mW				
Output	Load voltage (DC)	V_L	40 V	60 V	250 V	400 V	
	Continuous load current (DC)	I_L	0.7 A	0.6 A	0.3 A	0.18 A	
	Peak load current	I_{peak}	1.8 A	1.5 A	0.6 A	0.5 A	100 ms (1 shot)
	Power dissipation	P_{out}	360 mW				
Total power dissipation		P_T	410 mW				
I/O isolation voltage		V_{iso}	1,500 V (AC)				
Temperature limits	Operating	T_{opr}	-40°C to +85°C -40°F to +185°F				Non-condensing at low temperatures
	Storage	T_{stg}	-40°C to +100°C -40°F to +212°F				

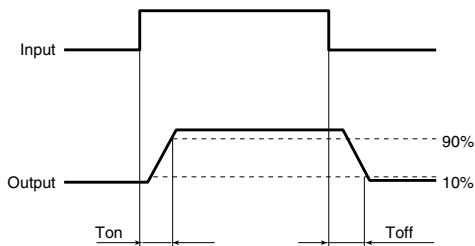
2) Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQV101(A)	AQV102(A)	AQV103(A)	AQV104(A)	Condition	
Input	LED operate current	Typical	I_{Fon}	2.3 mA				$I_L = \text{Max.}$	
		Maximum		5 mA					
	LED turn off current	Minimum	I_{Foff}	0.8 mA				$I_L = \text{Max.}$	
		Typical		2.2 mA					
LED dropout voltage	Typical	V_F	2.3 V				$I_F = 10 \text{ mA}$		
	Maximum		3 V						
Output	On resistance	Typical	R_{on}	0.3 Ω	0.37 Ω	2.7 Ω	6.3 Ω	$I_F = 10 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s on time	
		Maximum		0.5 Ω	0.7 Ω	4 Ω	8 Ω		
Off state leakage current		Maximum	—	1 μA				$I_F = 0 \text{ mA}$, $V_L = \text{Max.}$	
Transfer characteristics	Switching speed	Turn on time*	Typical	0.23 ms	0.22 ms	0.13 ms	0.09 ms	$I_F = 10 \text{ mA}$ $I_L = \text{Max.}$	
			Maximum	1 ms					
	Turn off time*	Typical	T_{off}	0.07 ms			0.08 ms	$I_F = 10 \text{ mA}$ $I_L = \text{Max.}$	
		Maximum		1 ms					
	I/O capacitance		Typical	C_{iso}	1.3 pF				f = 1 MHz $V_B = 0 \text{ V}$
			Maximum		3 pF				
Initial I/O isolation resistance		Minimum	R_{iso}	1,000 MΩ				500 V DC	

Note: Recommendable LED forward current $I_F = 10 \text{ mA}$.

For type of connection.

*Turn on/Turn off time



HF PhotoMOS (AQV100, 200)

2. AC/DC type (AQV20 types)

1) Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV201(A)	AQV202(A)	AQV203(A)	AQV204(A)	Remarks	
Input	LED forward current	I_F		50 mA				f = 100 Hz, Duty factor = 0.1%	
	LED reverse voltage	V_R		10 V					
	Peak forward current	I_{FP}		1 A					
	Power dissipation	P_{in}		150 mW					
Output	Load voltage (peak AC)	V_L		40 V	60 V	250 V	400 V	A connection: Peak AC, DC B, C connection: DC	
	Continuous load current	I_L		A	0.5 A	0.4 A	0.2 A		0.15 A
				B	0.7 A	0.6 A	0.3 A		0.18 A
				C	1.0 A	0.8 A	0.4 A		0.25 A
	Peak load current	I_{peak}			1.8 A	1.5 A	0.6 A		0.5 A
Power dissipation	P_{out}		360 mW						
Total power dissipation		P_T		410 mW					
I/O isolation voltage		V_{iso}		1,500 V AC					
Temperature limits	Operating	T_{opr}		-40°C to +85°C -40°F to +185°F				Non-condensing at low temperature	
	Storage	T_{stg}		-40°C to +100°C -40°F to +212°F					

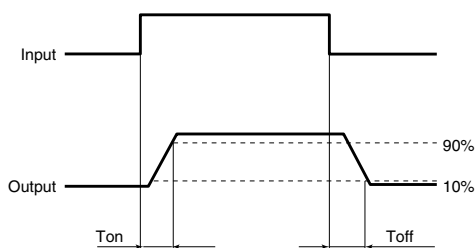
2) Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV201(A)	AQV202(A)	AQV203(A)	AQV204(A)	Remarks		
Input	LED operate current	Typical	I_{Fon}	—	2.4 mA				$I_L = Max.$	
		Maximum			5 mA					
	LED turn off current	Minimum	I_{Foff}	—	0.8 mA				$I_L = Max.$	
		Typical			2.2 mA					
LED dropout voltage	Typical	V_F	—	2.3 V				$I_F = 10 mA$		
	Maximum			3 V						
Output	On resistance	Typical	R_{on}	A	0.6 Ω	0.74 Ω	5.5 Ω	12.4 Ω	$I_F = 10 mA$ $I_L = Max.$ Within 1 s on time	
		Maximum			1 Ω	1.4 Ω	8 Ω	16 Ω		
		Typical	R_{on}	B	0.3 Ω	0.37 Ω	2.7 Ω	6.2 Ω	$I_F = 10 mA$ $I_L = Max.$ Within 1 s on time	
		Maximum			0.5 Ω	0.7 Ω	4 Ω	8 Ω		
		Typical	R_{on}	C	0.15 Ω	0.18 Ω	1.4 Ω	3.1 Ω	$I_F = 10 mA$ $I_L = Max.$ Within 1 s on time	
		Maximum			0.25 Ω	0.35 Ω	2 Ω	4 Ω		
Off state leakage current		Maximum	—	—	1 μA				$I_F = 0 mA$, $V_L = Max.$	
Transfer characteristics	Switching speed	Turn on time*	Typical	T_{on}	—	0.38 ms	0.41 ms	0.21 ms	0.18 ms	$I_F = 10 mA$ $I_L = Max.$
			Maximum			1 ms				
		Turn off time*	Typical	T_{off}	—	0.08 ms		0.07 ms		$I_F = 10 mA$ $I_L = Max.$
			Maximum			1 ms				
	I/O capacitance		Typical	C_{iso}	—	1.3 pF				f = 1 MHz $V_B = 0 V$
		Maximum	3 pF							
Initial I/O isolation resistance		Minimum	R_{iso}	—	1,000 MΩ				500 V DC	

Note: Recommendable LED forward current $I_F = 10 mA$.

For type of connection.

*Turn on/Turn off time



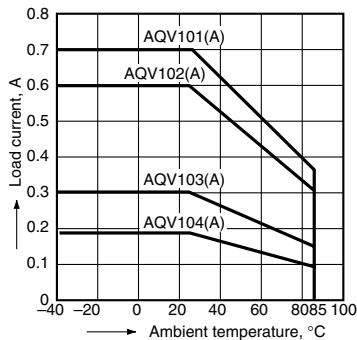
- For Dimensions.
- For Schematic and Wiring Diagrams.
- For Cautions for Use.

HF PhotoMOS (AQV100, 200)

REFERENCE DATA

1.-(1) Load current vs. ambient temperature characteristics (DC type)

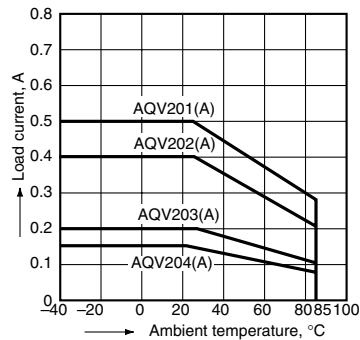
Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



1.-(2) Load current vs. ambient temperature characteristics (AC/DC type)

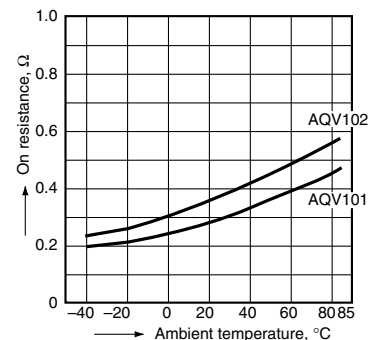
Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F

Type of connection: A



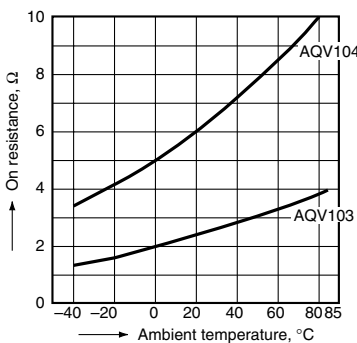
2.-(1) On resistance vs. ambient temperature characteristics (DC type: AQV101, AQV102)

LED current: 10 mA;
Continuous load current: Max. (DC)



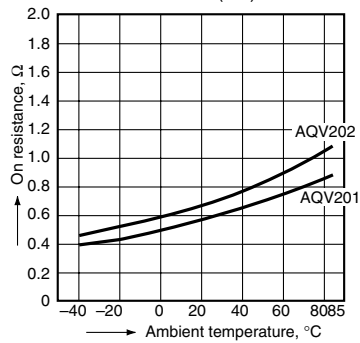
2.-(2) On resistance vs. ambient temperature characteristics (DC type: AQV103, AQV104)

LED current: 10 mA;
Continuous load current: Max. (DC)



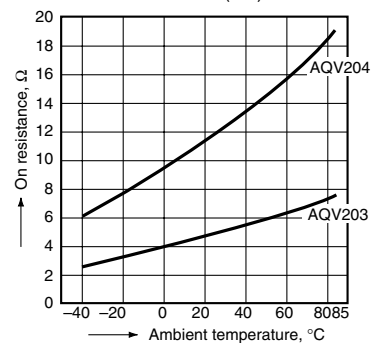
2.-(3) On resistance vs. ambient temperature characteristics (AC/DC type: AQV201, AQV202)

Measured portion: between terminals 4 and 6;
LED current: 10 mA;
Continuous load current: Max. (DC)



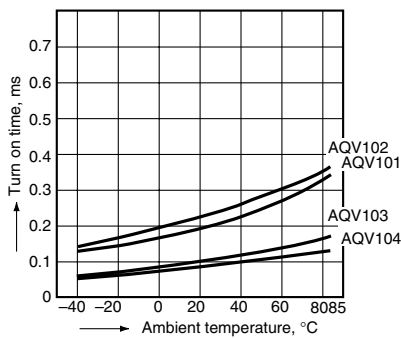
2.-(4) On resistance vs. ambient temperature characteristics (AC/DC type: AQV203, AQV204)

Measured portion: between terminals 4 and 6;
LED current: 10 mA;
Continuous load current: Max. (DC)



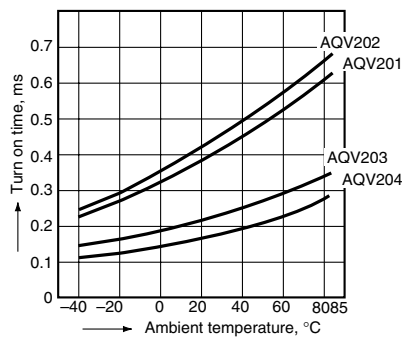
3.-(1) Turn on time vs. ambient temperature characteristics (DC type)

LED current: 10 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



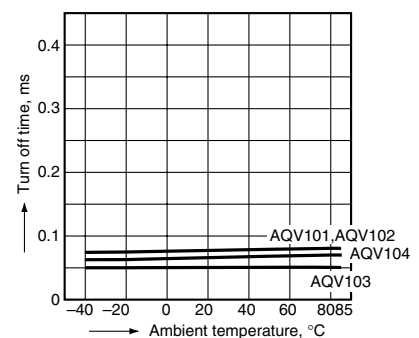
3.-(2) Turn on time vs. ambient temperature characteristics (AC/DC type)

LED current: 10 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



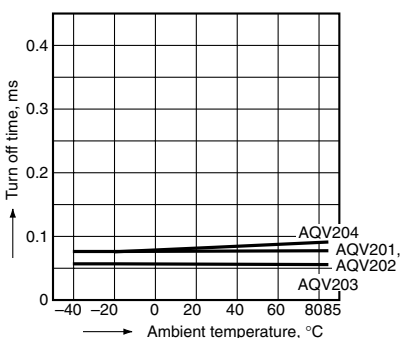
4.-(1) Turn off time vs. ambient temperature characteristics (DC type)

LED current: 10 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



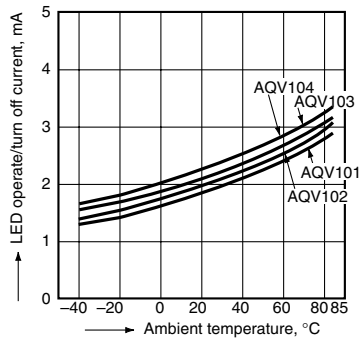
4.-(2) Turn off time vs. ambient temperature characteristics (AC/DC type)

LED current: 10 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



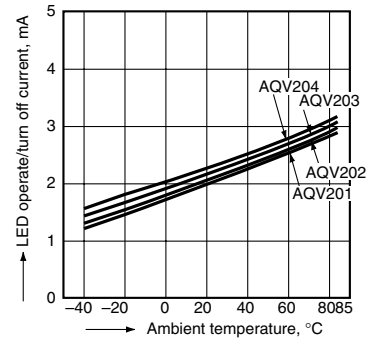
5.-(1) LED operate/turn off current vs. ambient temperature characteristics (DC type)

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



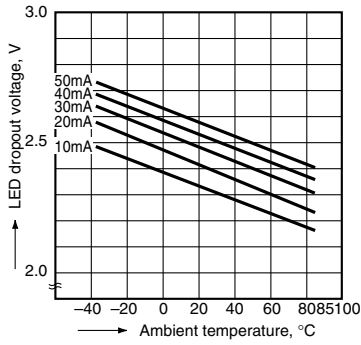
5.-(2) LED operate/turn off current vs. ambient temperature characteristics (AC/DC type)

Load voltage: Max. (DC);
Continuous load current: Max. (DC)

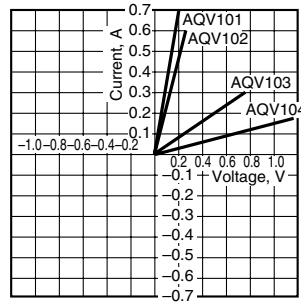


HF PhotoMOS (AQV100, 200)

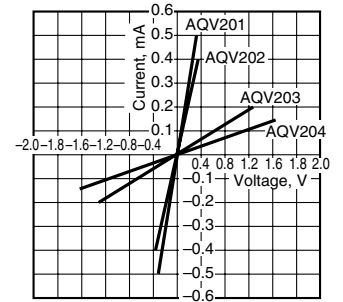
6. LED dropout voltage vs. ambient temperature characteristics
 Sample: AQV202
 LED current: 10 to 50 mA



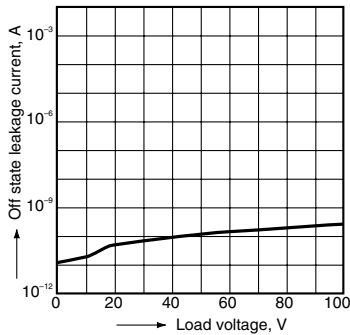
7.-(1) Current vs. voltage characteristics of output at MOS portion (DC type)
 Ambient temperature: 25°C 77°F



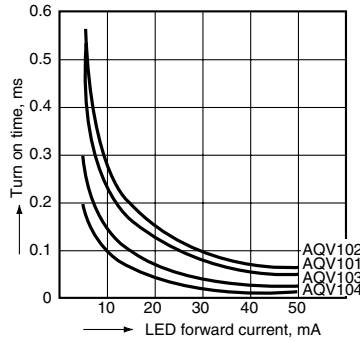
7.-(2) Current vs. voltage characteristics of output at MOS portion (AC/DC type)
 Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



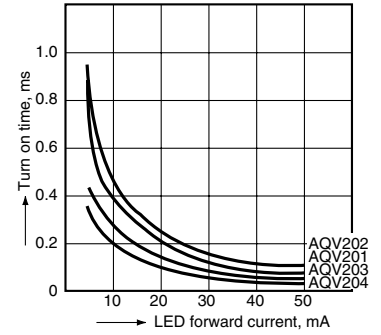
8. Off state leakage current vs. load voltage characteristics
 Sample: AQV204;
 Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



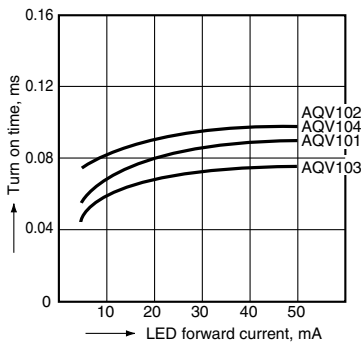
9.-(1) Turn on time vs. LED forward current characteristics (DC type)
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC);
 Ambient temperature: 25°C 77°F



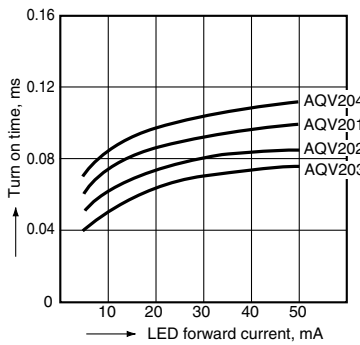
9.-(2) Turn on time vs. LED forward current characteristics (AC/DC type)
 Measured portion: between terminals 4 and 6;
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC);
 Ambient temperature: 25°C 77°F



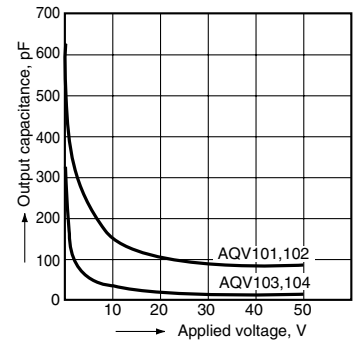
10.-(1) Turn off time vs. LED forward current characteristics (DC type)
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC);
 Ambient temperature: 25°C 77°F



10.-(2) Turn off time vs. LED forward current characteristics (AC/DC type)
 Measured portion: between terminals 4 and 6;
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC);
 Ambient temperature: 25°C 77°F



11.-(1) Output capacitance vs. applied voltage characteristics (DC type)
 Frequency: 1 MHz;
 Ambient temperature: 25°C 77°F



11.-(2) Output capacitance vs. applied voltage characteristics (AC/DC type)
 Measured portion: between terminals 4 and 6;
 Frequency: 1 MHz;
 Ambient temperature: 25°C 77°F

